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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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# Tyco / Electronics Raychem Circuit Protection 308 Constitution Drive

Menlo Park, CA 94025-1164 Phone: 800-227-4856

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# SiBar<sup>™</sup> Thyristor Surge Protectors

PRODUCT: TVB170SA

DOCUMENT: SCD 24303

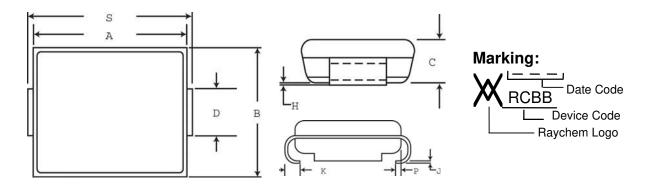
PCN: 958923 REV LETTER: D

REV DATE: AUGUST 24, 2004

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### **Specification Status: RELEASED**

### PHYSICAL DESCRIPTION



	Α		A B C		;	D**		Н		J		K		
	MIN	MAX												
mm:	4.06	4.57	3.30	3.81	1.90	2.41	1.96	2.11	0.051	0.152	0.15	0.30	0.76	1.27
in*:	(0.160)	(0.180)	(0.130)	(0.150)	(0.075)	(0.095)	(0.077)	(0.083)	(0.002)	(0.006)	(0.006)	(0.012)	(0.030)	(0.050)

	Р	S					
	REF	MIN	MAX				
mm:	0.51	5.21	5.59				
in*:	(0.020)	(0.205)	(0.220)				

<sup>\*</sup>Rounded off approximation

### **Other Physical Characteristics**

Form Factor: SMB (Surface Mount, JEDEC DO-214AA Package)

Lead Material: Tin/lead finish

Encapsulation Material: Epoxy, meets UL94 V-0 requirements Solderability: per MIL-STD-750, Method 2026 per MIL-STD-750, Method 2031 solvent Resistance: per MIL-STD-750, Method 1022 per MIL-STD-750, Method 2016 vibration: per MIL-STD-750, Method 2056

Tape and Reel packaging per EIA 481-1

Agency Recognition: UL

Precedence: This specification takes precedence over documents referenced herein.

CAUTION: Operation beyond the rated voltage or current may result in rupture, electrical arcing or flame.

### **Materials Information**

**ELV Compliant** 

Directive 2000/53/EC Compliant

<sup>\*\*</sup>D DIMENSION SHALL BE MEASURED WITHIN DIMENSION P

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### **DEVICE RATINGS @ 25º C (Both Polarities)**

	Parameter	Symbol	Value	Units
Repetitive off-State Voltage, Maximum at ID = 5 μA			170	V
Non-Repetitive Peak	Telcordia GR-1089 CORE 10x1000 μs	IPP <sub>1</sub>	50	Α
Impulse Current	TIA-968 lightning Type A Metallic 10/560 µs	IPP <sub>2</sub>	70	Α
Double exponential	TIA-968 lightning Type A Longit. 10/160 μs	IPP <sub>3</sub>	100	Α
Waveform	Telcordia GR-1089 Intrabuilding 2/10 μs	IPP₄	150	Α
(Notes 1 and 2)	IEC61000-4-5 (Voc 1.2/50us) 8/20 μs	IPP <sub>5</sub>	150	Α
	ITU-T K.20/K.21 (Voc 10/700us) 5/310μs	IPP <sub>6</sub>	90	Α
	TIA-968 lightning Type B (Voc 9/720us) 5/320 μs	IPP <sub>7</sub>	90	Α
Critical Rate of Rise of				
Powered Pulse Amplific	di/dt	500	A/μs	
Maximum 2x10 µsec w	di/dt	110	A/μs	

### **DEVICE THERMAL RATINGS**

Storage Temperature Range		-55 to 150	∘C
Operating Temperature Range		-40 to 125	∘C
Blocking or conducting state			
Overload Junction Temperature		+150	ōC
Maximum; Conducting state only			
Maximum Lead Temperature for Soldering Purpose; for 10 seconds		+260	ōC

### ELECTRICAL CHARACTERISTICS Both polarities (T<sub>J</sub> @ 25°C unless otherwise noted)

Characteristics	Symbol	Min	Тур	Max	Units
Breakover Voltage (+25°C)	VBO		230	265	V
$(dv/dt = 0.4kV/\mu sec, I_{SC}=900mA, V_{DC} = 500V (both polarities))$					
Breakover Voltage Temperature Coefficient	dVBO/dTJ		0.1		%/ºC
Off-State Current (VD1=50V)	ID1			2.0	μΑ
(VD2=VDM)	ID2=IDM			5.0	μΑ
On-State Voltage (IT=1A	VT			4.0	V
(PW ≤ 300 µsec, Duty Cycle ≤ 2% (Note 2))					
Breakover Current	IBO			800	mA
Holding Current (Note 2)	IH	150			mA
Peak Onstage Surge Current	ITSM	22			Α
(Measured @ 60Hz, 1 cycle, 600V)					
Critical Rate of Rise of Off-State Voltage	dv/dt	2000			V/µs
(Linear waveform, $V_D = 0.8 \text{ X Rated } V_{BO}, T_{J} = +25^{\circ}\text{C}$ )					
Capacitance (f=1.0 Mhz, 50V <sub>DC</sub> bias, 1Vrms)	C1		18		pF
(f=1.0 Mhz, 2V <sub>DC</sub> bias, 1Vrms)	C2		35		pF

Note 1. Allow cooling before test second polarity

Note 2. Measured under pulse conditions to reduce heating

### **VOLTAGE-CURRENT CHARACTERISTIC**

